onsemi

MARKING DIAGRAMS

TinyLogic HS 2-Input AND Gate

NC7S08

Description

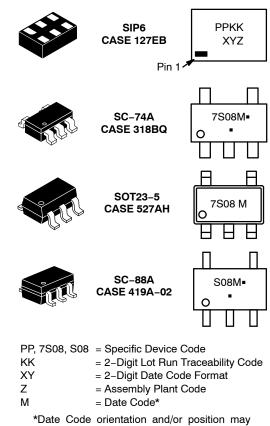
The NC7S08 is a single 2–Input high performance CMOS AND Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. Three stages of gain between inputs and outputs assures high noise immunity and reduced sensitivity to input edge rate.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPak[™] Leadless Package
- High Speed: $t_{PD} = 3.5$ ns Typ
- Low Quiescent Power: $I_{CC} < 1 \mu A$
- Balanced Output Drive: 2 mA I_{OL}, -2 mA I_{OH}
- Broad V_{CC} Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol

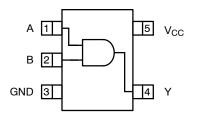


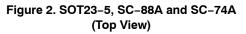
*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

Pin Configurations





PIN DESCRIPTION

Pin Names	Description
A, B	Inputs
Y	Output
NC	No Connect

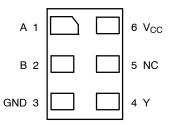


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE (Y = AB)

Inp	Output	
А	В	Y
L	L	L
L	н	L
н	L	L
Н	Н	Н

H = HIGH Logic Level L = LOW Logic Level

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current V _{IN} < 0 V		-	-20	mA
		V _{IN} > V _{CC}	-	+20	
V _{IN}	DC Input Voltage	•	-0.5	V _{CC} + 0.5	V
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-20	mA
		V _{OUT} > V _{CC}	-	+20	
V _{OUT}	DC Output Voltage	•	-0.5	V _{CC} + 0.5	V
I _{OUT}	DC Output Source or Sink Current		-	±12.5	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current per Output	ıt Pin	-	±25	mA
T _{STG}	Storage Temperature		-65	+150	°C
ТJ	Junction Temperature		-	+150	°C
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C
PD	Power Dissipation in Still Air SC-74A / SOT23-5		-	390	mW
		SC-88A	-	332	
		MicroPak-6	-	812	

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NC7S08

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		2.0	6.0	V
V _{IN}	Input Voltage		0	V _{CC}	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} at 2.0 V	0	20	ns/V
		V _{CC} at 3.0 V	0	20	
		V _{CC} at 4.5 V	0	10	
		V _{CC} at 6.0 V	0	5	
θ_{JA}	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

DC ELECTICAL CHARACTERISTICS

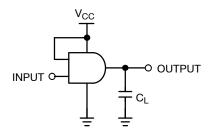
				1	「 _A = +25°0		$T_A = -40 \text{ to } +85^{\circ}C$		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage	2.0		1.50	-	-	1.50	-	V
		3.0 - 6.0		$0.7 \times V_{CC}$	-	-	$0.7 \times V_{CC}$	-	
VIL	LOW Level Input Voltage	2.0		-	-	0.50	-	0.50	V
		3.0 - 6.0		-	-	$0.3 \times V_{CC}$	-	$0.3 \times V_{CC}$	
V _{OH}	HIGH Level Output Voltage	2.0	I _{OH} = -20 μA,	1.90	2.0	-	1.90	-	V
		3.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$	2.90	3.0	-	2.90	-	
		4.5		4.40	4.5	-	4.40	-	
		6.0	6.0	5.90	6.0	-	5.90	-	
		3.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OH} = -1.3 \text{ mA}$	2.68	2.85	-	2.63	-	
		4.5	$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL}, \\ I_{OH} = -2 \text{ mA} \end{array}$	4.18	4.35	-	4.13	-	
		6.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OH} = -2.6 \text{ mA}$	5.68	5.85	-	5.63	-	
V _{OL}	LOW Level Output Voltage	2.0	l _{OL} = 20 μA,	-	0.0	0.10	-	0.10	V
		3.0	$V_{IN} = V_{IH}$ or V_{IL}	-	0.0	0.10	-	0.10	
		4.5		-	0.0	0.10	-	0.10	
		6.0		-	0.0	0.10	-	0.10	
		3.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OH} = 1.3 \text{ mA}$	-	0.1	0.26	-	0.33	
		4.5	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OL} = 2 \text{ mA}$	-	0.1	0.26	_	0.33	
		6.0	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $I_{OL} = 2.6 \text{ mA}$	-	0.1	0.26	_	0.33	
I _{IN}	Input Leakage Current	6.0	V _{IN} = V _{CC} , GND	-	-	±0.1	-	±1.0	μA
I _{CC}	Quiescent Supply Current	6.0	V _{IN} = V _{CC} , GND	-	-	1.0	-	10.0	μA

AC ELECTRICAL CHARACTERISTICS

			T _A = +25°C		$T_A = +25^{\circ}C$ $T_A = -40 \text{ to } +85^{\circ}C$		$T_{A} = +25^{\circ}C \qquad T_{A} = -4$		$T_A = +25^{\circ}C$ $T_A = -40$ to +85		to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit			
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 6)	5.0	C _L = 15 pF	-	3.5	15	-	-	ns			
		2.0	C _L = 50 pF	-	20	100	-	125				
		3.0		-	11	27	-	35				
		4.5		-	8	20	-	25				
		6.0		-	7	17	-	21				
t _{TLH} , t _{THL}	Output Transition Time	5.0	C _L = 15 pF	-	3.0	10	-	-	ns			
	(Figure 4, 6)	2.0	C _L = 50 pF	-	25	125	-	155				
		3.0		-	16	35	-	45				
		4.5		-	11	25	-	31				
		6.0		-	9	21	-	26				
C _{IN}	Input Capacitance	Open		-	2	10	-	10	pF			
C _{PD}	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	_	6	-	-	-	pF			

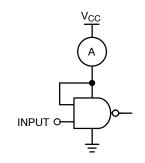
2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



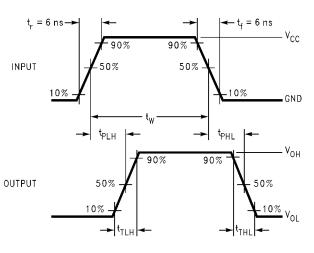
 C_L includes load and stray capacitance Input PRR = 1.0 MHz, t_W = 500 ns

Figure 4. AC Test Circuit



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit





DEVICE ORDERING INFORMATION

Device	Top Mark	Packages	Shipping [†]
NC7S08M5X	7S08	SC-74A	3000 / Tape & Reel
NC7S08M5X-L22090	7S08	SOT23-5	3000 / Tape & Reel
NC7S08P5X	S08	SC-88A	3000 / Tape & Reel
NC7S08P5X-F22057	S08	SC-88A	3000 / Tape & Reel
NC7S08L6X	PP	SIP6, MicroPak	5000 / Tape & Reel
NC7S08L6X-L22175	PP	SIP6, MicroPak	5000 / Tape & Reel

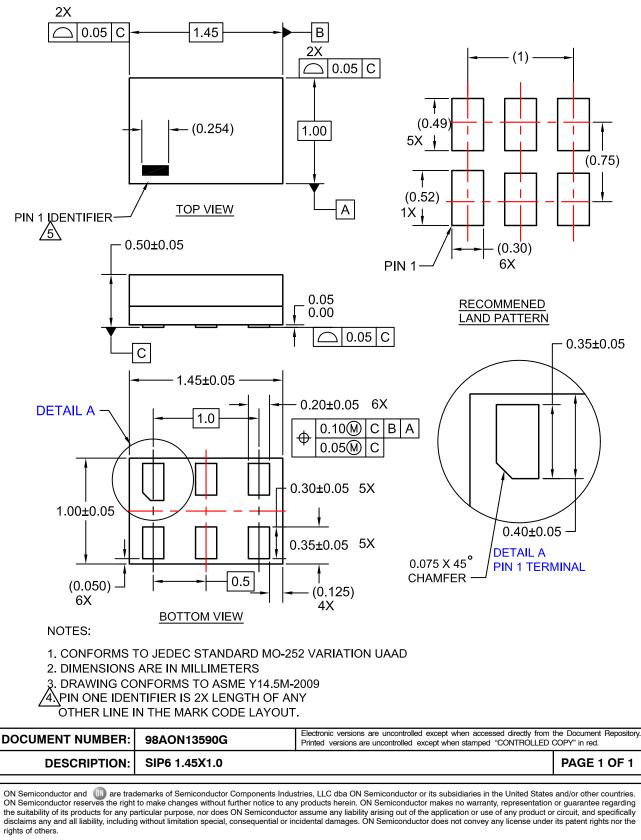
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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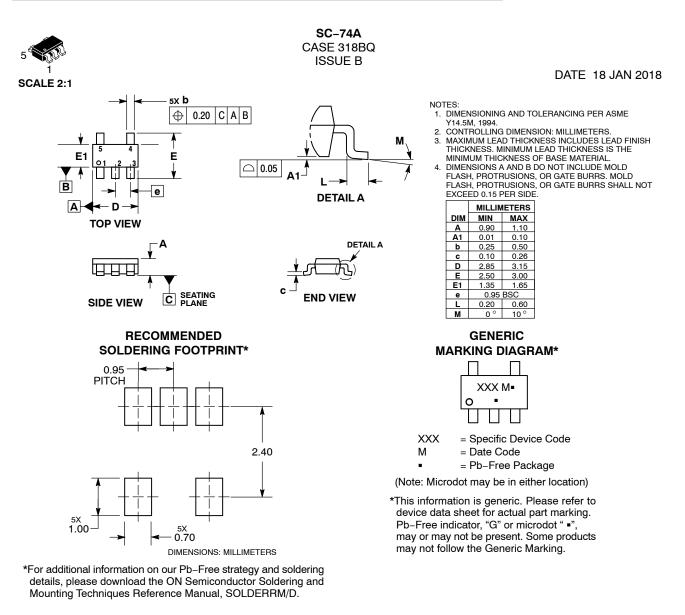


SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016







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DATE 11 APR 2023

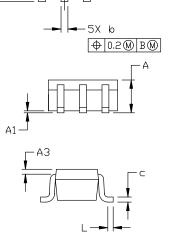


SCALE 2:1

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

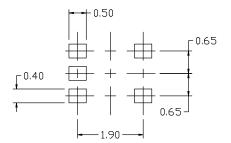
NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE. NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.



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F1



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our
Pb-Free strategy and soldering details,
please download the DN Semiconductor
Soldering and Mounting Techniques
Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS			
ויונע	MIN.	NDM.	MAX,	
A	0.80	0.95	1.10	
A1			0.10	
A3		0.20 REF		
b	0.10	0.20	0,30	
C	0.10		0,25	
D	1.80	2.00	5.20	
E	2.00	2.10	5.20	
E1	1.15	1.25	1.35	
e	0.65 BSC			
L	0.10	0.15	0.30	

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 1. ANODE PIN 1. ANODE 1 PIN 1. SOURCE 1 PIN 1. CATHODE 2. EMITTER 2. EMITTER 2. N/C 2. DRAIN 1/2 2. COMMON ANODE 3. BASE 3. BASE 3. ANODE 2 3. SOURCE 1 3. CATHODE 2 4. COLLECTOR 4. COLLECTOR 4. CATHODE 2 4. GATE 1 4. CATHODE 3 5. COLLECTOR 5. CATHODE 5. CATHODE 1 5. GATE 2 5. CATHODE 4 STYLE 6: STYLE 7: STYLE 8: STYLE 9: Note: Please refer to datasheet for style callout. If style type is not callout. COLLECTOR 3. EMITTER 1 3. BASE 3. N/C 3. ANODE 2 CATHODE 4. COLLECTOR 4. COLLECTOR 4. BASE 4. ANODE 3 out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not callout. COLLECTOR 4. COLLECTOR 4. COLLECTOR 5. EMITTER 5. ANODE out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. COLLECTOR 5. COLLECTOR 2/BASE 1 5. COLLECTOR 5. EMITTER 5. ANODE out in the datasheet refer to the callout. If style type is not callout. If style type is not callout. If style type is not call	DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1
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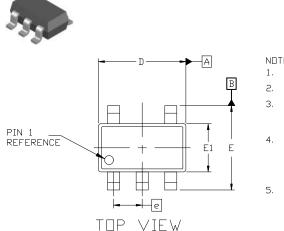
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XXX = Specific Device Code

M = Date Code = Pb-Free Package

⁽Note: Microdot may be in either location)



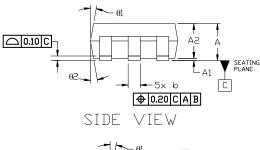


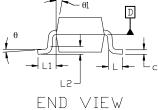


DATE 09 JUN 2021

NDTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- DIMENSION 'b' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE 'b' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.





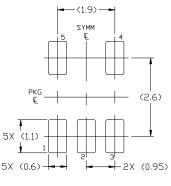
GENERIC **MARKING DIAGRAM***



XXX = Specific Device Code = Date Code М

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
А	0.90	—	1.45	
A1	0.00	_	0.15	
A2	0.90	1.15	1.30	
b	0.30	—	0.50	
С	0.08	—	0.22	
D	2.90 BSC			
E	2.80 BSC			
E1	1.60 BSC			
e	0.95 BSC			
L	0.30	0.45	0.60	
L1	0.60 REF			
L2	0.25 REF			
θ	0*	4°	8*	
θ1	0°	10°	15°	
θ2	0*	10°	15°	



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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